



**SDI Review Form 1.6**

Journal Name:	<a href="#">Physical Science International Journal</a>
Manuscript Number:	2014_PSIJ_8904
Title of the Manuscript:	<b>Random Telegraph Signals Generated in Transistors Due to Gamma Ray Irradiation: Online Study of the Device Characteristics</b>
Type of the Article	<b>Original Research Article</b>

**General guideline for Peer Review process:**

This journal's peer review policy states that **NO** manuscript should be rejected only on the basis of '**lack of Novelty**', provided the manuscript is scientifically robust and technically sound.

To know the complete guideline for Peer Review process, reviewers are requested to visit this link:

(<http://www.sciencedomain.org/page.php?id=sdi-general-editorial-policy#Peer-Review-Guideline>)



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**PART 1: Review Comments**

	Reviewer's comment	Author's comment (if agreed with reviewer, correct the manuscript and highlight that part in the manuscript. It is mandatory that authors should write his/her feedback here)
<b><u>Compulsory</u></b> REVISION comments	The effect of radiation is often on the electronic circuits that are close to radioactive sources, especially in the nuclear labs. The protons or alpha particles or beta particles have no effect on the properties of electronic unless the nuclear radiation be of high energies and direct on electronic circuits because the plasma formed from these particles are close to the surface of the material, but gamma rays as possible penetrate the area of potential barrier and events influence.	
<b><u>Minor</u></b> REVISION comments	I think the effect of nuclear radiation is clear in the case of irradiation of the second and third time.	
<b><u>Optional/General</u></b> comments	The paper is important because the effect of radiation on the electronic properties sometimes have a negative impact on the practical results.	

**Note: Anonymous Reviewer**